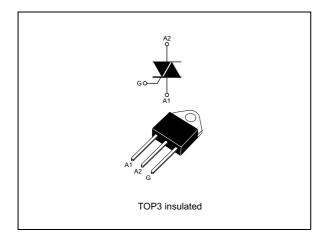


TPDVxx40

40 A high voltage Triacs

Datasheet - production data



Features

- On-state current (I_{T(RMS)}): 40 A
- Max. blocking voltage (V_{DRM}/V_{RRM}): 1200 V
- Gate current (I_{GT}): 200 mA
- Commutation at 10 V/µs: up to 142 A/ms
- Noise immunity: 500 V/µs
- Insulated package:
 - 2,500 V rms (UL recognized: E81734)

Description

The TPDVxx40 series use a high performance alternistor technology. Featuring very high commutation levels and high surge current capability, this family is well adapted to power control on inductive load (motor, transformer...).

Parameter	Blocking voltage V _{DRM} /V _{RRM}	On-state current I _{T(RMS)}	Gate current I _{GT}
TPDV640RG	600 V		
TPDV840RG	800 V	40 A	200 mA
TPDV1240RG	1200 V		

This is information on a product in full production.

1 Characteristics

Symbol	Parameter			Value	Unit
I _{T(RMS)}	On-state rms current (180° conduction a	angle)	T _c = 75 °C	40	А
		t _p = 2.5 ms		590	A
I _{TSM}	Non repetitive surge peak on-state current	t _p = 8.3 ms	T _j = 25 °C	370	
		t _p = 10 ms		350	
l ² t	I ² t value for fusing	t _p = 10 ms	T _j = 25 °C	610	A ² S
dl/dt	Critical rate of rise of on-state current $I_G = 500 \text{ mA}$; $dI_G/dt = 1 \text{ A}/\mu\text{s}$	Repetitive F =	Repetitive F = 50 Hz		A/µs
ui/ut		Non repetitive	Non repetitive		
	Repetitive peak off-state voltage	TPDV640	T _j = 125 °C	600	V
V _{DRM} V _{RRM}		TPDV840		800	
		TPDV1240		1200	
T _{stg} T _j	Storage junction temperature range Operating junction temperature range	-40 to +150 -40 to +125	°C		
TL	Maximum lead temperature for solderin	260	°C		
V _{INS(RMS)} ⁽¹⁾	Insulation rms voltage			2500	V

Table 2.	Absolute	ratings	(limitina	values))
			······································		,

1. A1, A2, gate terminals to case for 1 minute

Table 3. Electrical Characteristics ($T_j = 25$ °C, unless otherwise specified)

Symbol	Test condition		Quadrant		Value	Unit
I _{GT}	V _D = 12 V DC, R _L = 33 Ω		- -	Max.	200	mA
V _{GT}	$v_{\rm D} = 12 v DC, R_{\rm L} = 33 \Omega$		1 - 11 - 111	Max.	1.5	V
V _{GD}	$V_D = V_{DRM} R_L = 3.3 k\Omega$	T _j = 125 °C	- -	Min.	0.2	V
t _{gt}	$V_D = V_{DRM} I_G = 500 \text{ mA } dI_G/dt =$	3A/µs	- -	Тур.	2.5	μs
I _H ⁽¹⁾	I _T = 500 mA Gate open			Тур.	50	mA
	I_L $I_G = 1.2 \times I_{GT}$		-	Тур.	100	mA
'L			II		200	
dV/dt	Linear slope up to : $T_j = 125 \ ^{\circ}C$ $V_D = 67\% \ V_{DRM}$ Gate open $T_j = 125 \ ^{\circ}C$			Min.	500	V/µs
V _{TM} ⁽¹⁾	I _{TM} = 56 A t _p = 380 μs			Max.	1.8	V
I _{DRM}	$T_j = 25 \degree C$			Max.	20	μA
I _{RRM}	V _{DRM =} V _{RRM}	T _j = 125 °C		ινιάλ.	8	mA
(dl/dt)c ⁽¹⁾	(dV/dt)c = 200 V/µs T _i = 125 °C			Min.	35	A/ms
	(dV/dt)c = 10 V/µs	1j = 125 C			142	7/1115

1. For either polarity of electrode A_2 voltage with reference to electrode A_1 .

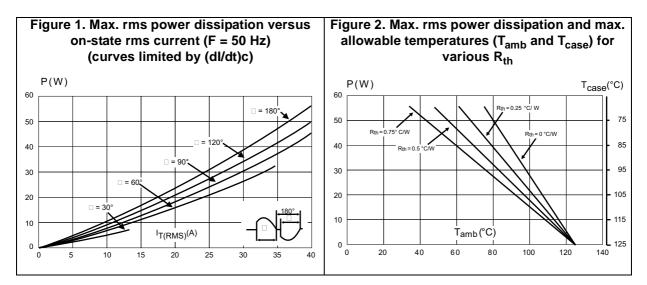


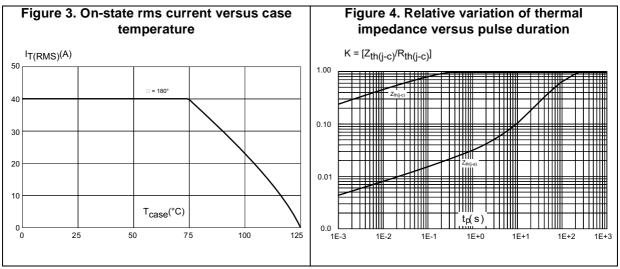
Symbol	Parameter	Parameter		Unit	
P _{G(AV)}	Average gate power dissipation	1	W		
P _{GM}	Peak gate power dissipation $t_p = 20 \ \mu s$		40	W	
I _{GM}	Peak gate current $t_p = 20 \ \mu s$		8	А	
V _{GM}	Peak positive gate voltage t _p = 20 µs		16	V	

Table 4. Gate characteristics (maximum values)

Table 5. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-a)}	Junction to ambient	50	°C/W
R _{th(j-c)} DC	Junction to case for DC	1.2	°C/W
R _{th(j-c)} AC	Junction to case for 360 °conduction angle (F = 50 Hz)	0.9	°C/W







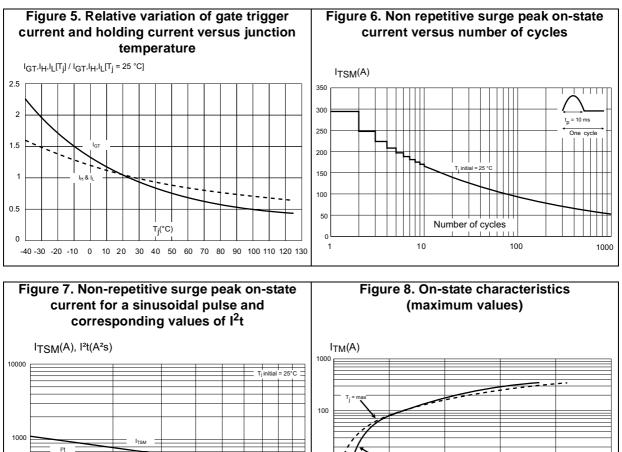
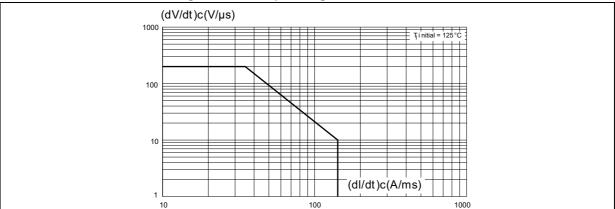
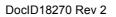


Figure 9. Safe operating area below curve







Tj max.: V₀ = 1.02V Re = 12m⊡

6

5

100

1

2 Package information

- Epoxy meets UL94, V0
- Cooling method:C (by conduction)
- Recommended torque value:0.9 to 1.2 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

2.1 TOP3 insulated package information

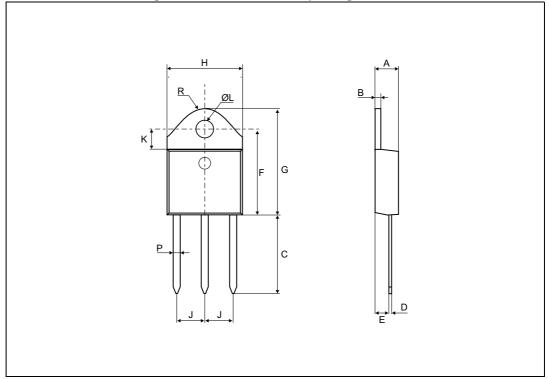


Figure 10. TOP3 insulated package outline



	Dimensions						
Ref.		Millimeters			Inches ⁽¹⁾		
	Тур.	Min.	Max.	Тур.	Min.	Max.	
А		4.4	4.6		0.173	0.181	
В		1.45	1.55		0.057	0.061	
С		14.35	15.60		0.565	0.614	
D		0.5	0.7		0.020	0.028	
E		2.7	2.9		0.106	0.114	
F		15.8	16.5		0.622	0.650	
G		20.4	21.1		0.815	0.831	
Н		15.1	15.5		0.594	0.610	
J		5.4	5.65		0.213	0.222	
К		3.4	3.65		0.134	0.144	
ØL		4.08	4.17		0.161	0.164	
Р		1.20	1.40		0.047	0.055	
R	4.60			0.181			

1. Values in inches are converted from mm and rounded to 4 decimal digits.



3 Ordering information

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Order code	Marking	Package	Weight	Base qty.	delivery mode	
TPDV640RG	TPDV640					
TPDV840RG	TPDV840	TOP3 insulated	4.5 g	30	Tube	
TPDV1240RG	TPDV1240					

Table 7. Ordering information

4 Revision history

Date	Revision	Changes
30-Mar-2011	1	Initial release.
10-Jun-2015	2	Updated <i>Table 3</i> . Updated <i>Figure 9</i> . Format updated to current standard.

Table 8. Document revision history



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